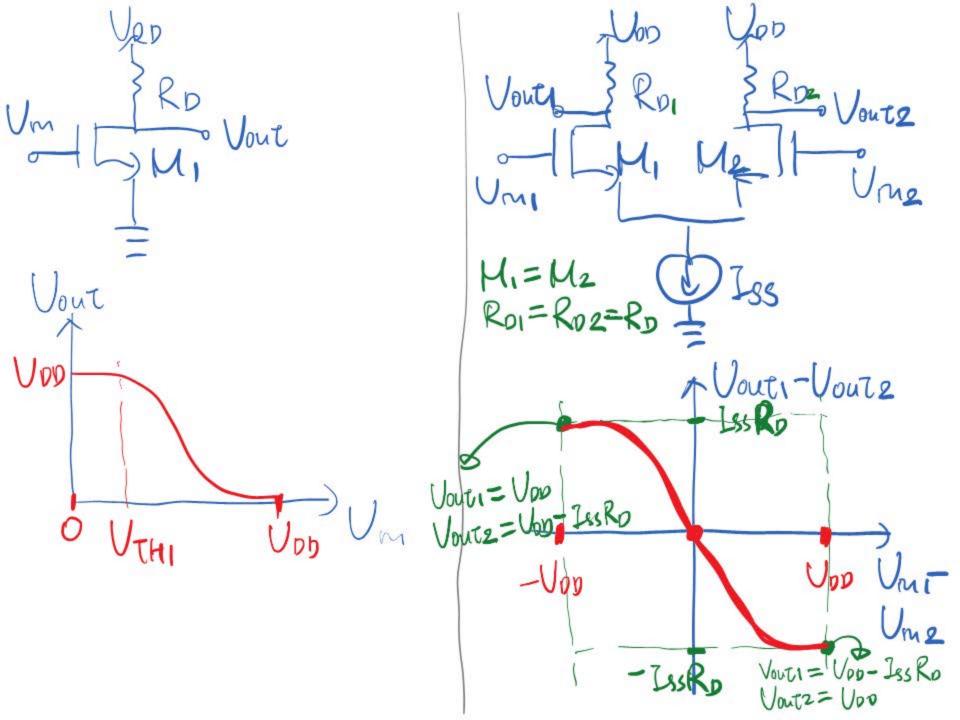
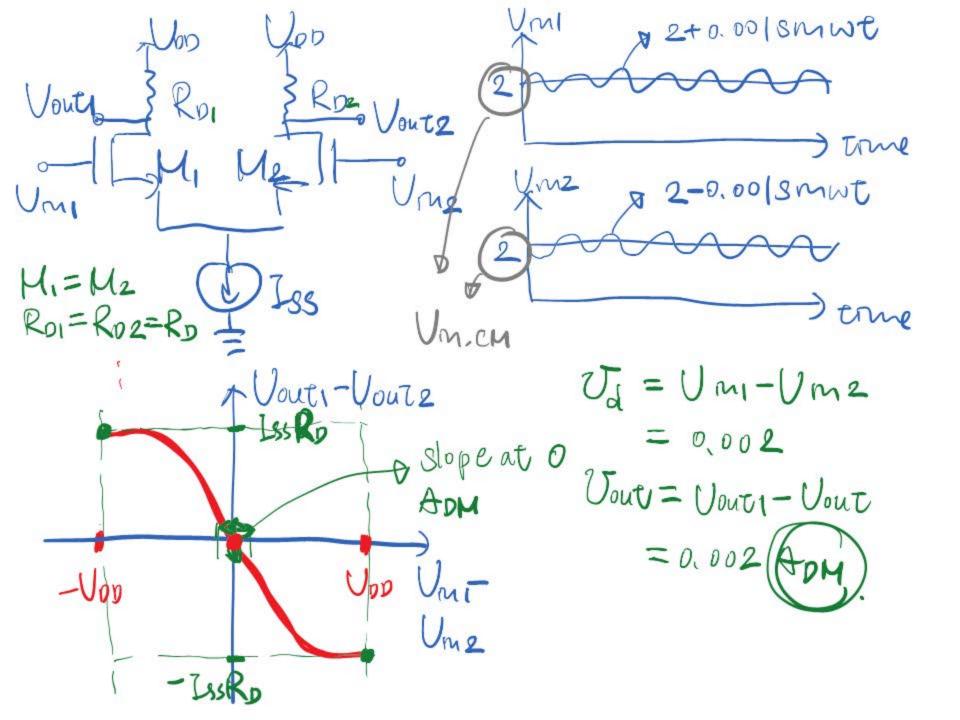
For the fried exam: ~ 10% upu BJT (CE, diode-connected load ~ 80% single stage anaiplifress etc.) based on NMOS and PMOS

< 10% differencial part

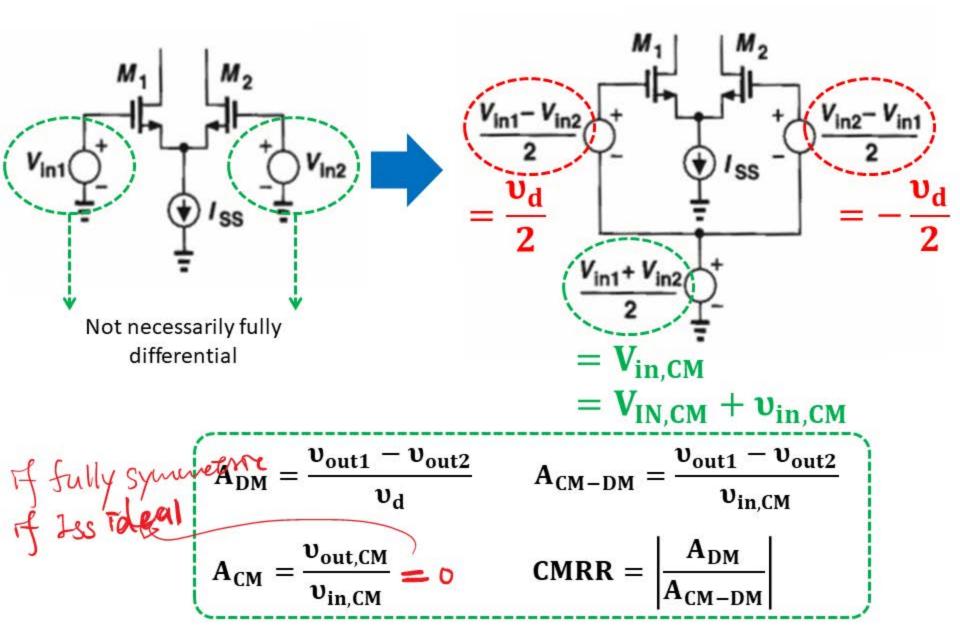


Vin= 2+ 0.00 | Sm (2100t) Vout = Vout + (0.001 Ab) sm (TUDOT) Assume x 2+0.00 (sm (2700t) & slope at Um=2 UOUT = 5 - (K) & LunCox (2-0.7)



Vd= Vm1-Um2=0,002 Um, eu = 2 = Umi+Umz 2 2-0.001Smwt. fully differential, a)+ (Tim, cy) Ud = Umi-Umz = AC Um, cu = Umit Um2 = VIN, CM) En, CM Not fully differential

Common-Mode + Differential-Mode



= Vout-Voute Vouty Ro. Ros Voute = Vout-Voute Umi-Uma Assume all on satural (Fo) (RoI=Rozko UI=M2) gm = gmz = gm1,2 101 = 102 = 10112 (Vout = - gm1,2 (01,2/1/RD) 50 Vour= - gm1,2 (to1,2//Ro) (- Ud)

l'Allmsaz. Vout 22 Fully symmetric (M2=U3, M4=U5) $3^{\circ} \Re = r = 0$. ADM = VOUTI-VOUT = -9m2,3 (1) gm2=gm3=gm2,3 gm4=gm5=gm4.5

Voue = Vouze = Voue 1,2 Assume all msate small (CM) (RoI=RozkoUI=M2)